E-MOSFET à Voltage Divider Blus

VDD 940V

Find, IDQ, V650, VDS,

VS, VD, V6D

VS, VD, V6D

Nos (Th)=5 V

ID (on)=3mA

V65(0n)=10V

RESPO-82K-2

 $\frac{18m2 \times 40}{V_{0}^{2}} = \frac{18m2 \times 40}{22m2 + 18m2} = \frac{18V}{22m2 + 18m2}$

Applying KVL, +V6-V65-IDRS=D => V65-IDRS => V65-IDRS=> V65-IDRS

We Know, ID= K(VGS-VT)'L -: ID= K(VGS- 5V)2----

Now,
$$k = \frac{ID(0n)}{(Nos(0n)-V_T)^2 - \frac{3mA}{(10V-5V)^2}}$$

$$= \frac{3x10^{-3}A}{(10V-5V)^2}$$

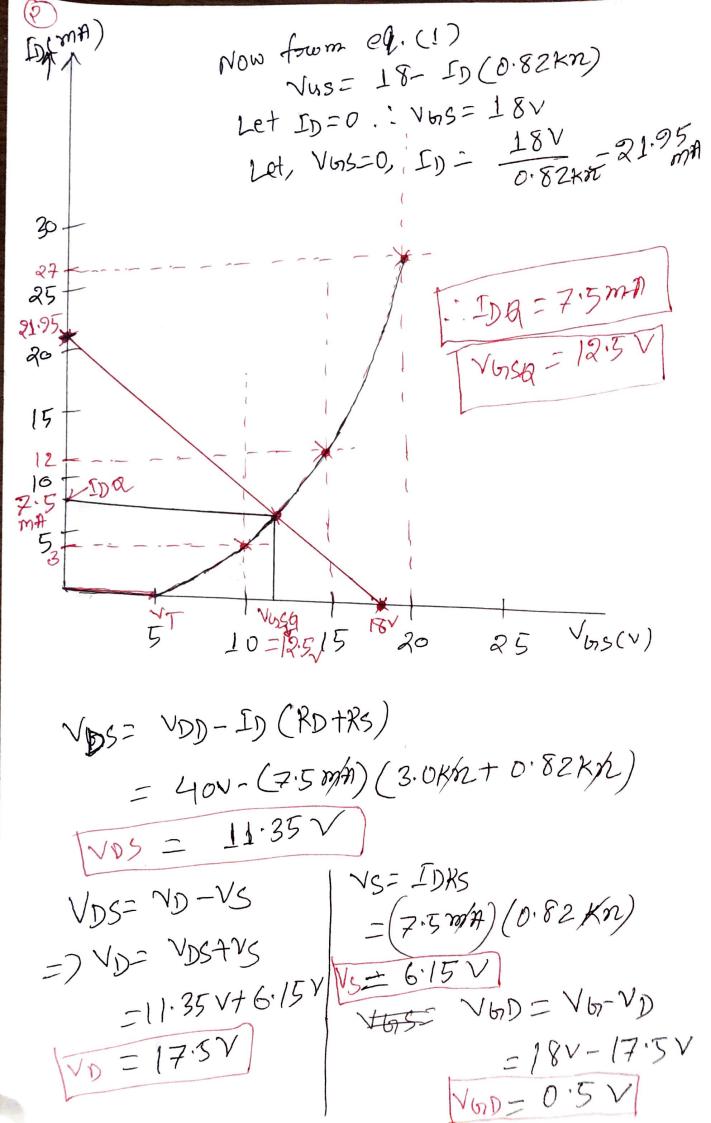
$$= 0.12x10^{-3}A/V^2$$
From equation (T)
$$ID = 0.12x10^{-3}(Nos - 5V)^2 - ...(II)$$
Now, we need to draw transfer characteristics curve from eq. (III).

From eq. (III),
Let, $V_{10} = 10V$

$$ID = 0.12x10^{-3}(10V-5V)^2 = 3mA$$
Let, $V_{10} = 15V$

$$ID = 0.12x10^{-3}(15-5)^2 = 12mA$$
Let, $V_{10} = 20V$

$$ID = 0.12x10^{-3}(20-5)^2 = 27mA$$
IN Next, we need to draw the transfer characteristics curve based on this point.



由 E-MOSFET Feedback Blus NDD of Tond, IDA, VOSA,

VRH, SRD=2KD

NDS, VD

Rb=10

Rb=10

D ID(0n)=6mH

Vus(bn)=8V

S Vus(th)=3V VRG= IGXRG= OXPG=0 1. VD= V67 OR 67=D Rh Applying KNL, = + VDS + IDRD - VDD=D VDS = VDD-IDAD VDS = VDD-IDAD -- (D [: G=D]

MG KNOW VIAS ID= K(VOS-V4)2---(17) ID(on) (VOS(67)-VT)2= (8V-3V)2 6×10-3A = (8V-3V)2 = 0.24 ×10-3A/V2 From Q(1) In= 0.24×103A/VV (VGS-3V)2--. (11) Let, Do VGS= GV 1. In= 0.24 ×10-34/22(6V-3V)2 = 2.16 mA Let, VGS= 8V ID= 0.24 ×10-3 A/V2 (8V-3V)2 = 6 mA Let Vos = 10 V : ID= 0.24×10-3A/V2(10-3V)2 = 11.76 mA

ID(mA) 1 12-11.76 11 10 : IDQ=3.4mA 9 8 V559=6.27 7 5 100 5 3.4mm 13:16] 23456789101112 >> VUS(V) VINSA= 62V From eq. (1) VUS= VDD - IDRD Let, ID=0, V65= VDD=12V Let V65=0, I) = $\frac{V00}{R0} = \frac{12V}{222}$ = 6 mA VDS=VD-VS VDS= VGS= 6.2V = DVD= VDS+ VS ND = 6.27 +0 VS= DV vj = 6.2V